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20 V, 1.0 A, Low V_{CE(sat)} NPN Transistor

ON Semiconductor's e²PowerEdge family of low $V_{CE(sat)}$ transistors are miniature surface mount devices featuring ultra low saturation voltage ($V_{CE(sat)}$) and high current gain capability. These are designed for use in low voltage, high speed switching applications where affordable efficient energy control is important.

Typical applications are DC–DC converters and power management in portable and battery powered products such as cellular and cordless phones, PDAs, computers, printers, digital cameras and MP3 players. Other applications are low voltage motor controls in mass storage products such as disc drives and tape drives. In the automotive industry they can be used in air bag deployment and in the instrument cluster. The high current gain allows e²PowerEdge devices to be driven directly from PMU's control outputs, and the Linear Gain (Beta) makes them ideal components in analog amplifiers.

Features

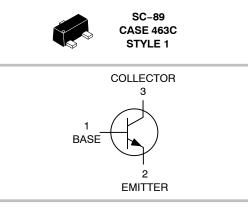
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant*



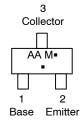
ON Semiconductor®

http://onsemi.com

20 VOLTS, 1.0 AMPS NPN LOW V_{CE(sat)} TRANSISTOR



MARKING DIAGRAM



AA = Specific Device Code

- M = Date Code*
- = Pb–Free Package

(Note: Microdot may be in either location)

*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
NSS20101JT1G	SC-89 (Pb-Free)	3,000 / Tape & Reel
NSV20101JT1G	SC-89 (Pb-Free)	3,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

Semiconductor Components Industries, LLC, 2013
May, 2013 – Rev. 3

MAXIMUM RATINGS (T_A = 25° C)

Rating	Symbol	Max	Unit	
Collector-Emitter Voltage	V _{CEO}	20	Vdc	
Collector-Base Voltage	V _{CBO}	40	Vdc	
Emitter-Base Voltage	V _{EBO}	6.0	Vdc	
Collector Current – Continuous	Ι _C	1.0	А	
Collector Current – Peak	I _{CM}	2.0	А	
Electrostatic Discharge	ESD	HBM Class 3B MM Class C		

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C	P _D (Note 1)	255 2.0	mW mW/°C
Thermal Resistance, Junction-to-Ambient	R _{θJA} (Note 1)	490	°C/W
Total Device Dissipation T _A = 25°C Derate above 25°C	P _D (Note 2)	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	R _{θJA} (Note 2)	415	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +150	°C

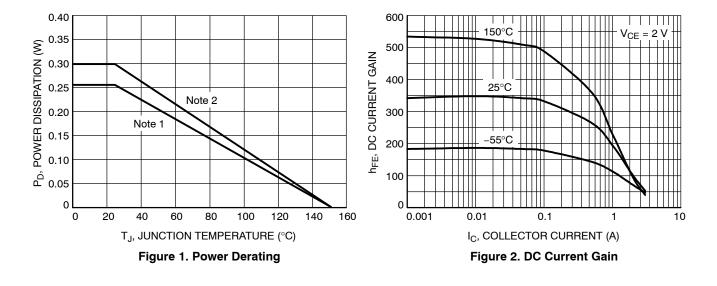
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability. 1. $FR-4 @ 100 \text{ mm}^2$, 1 oz. copper traces. 2. $FR-4 @ 500 \text{ mm}^2$, 1 oz. copper traces.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

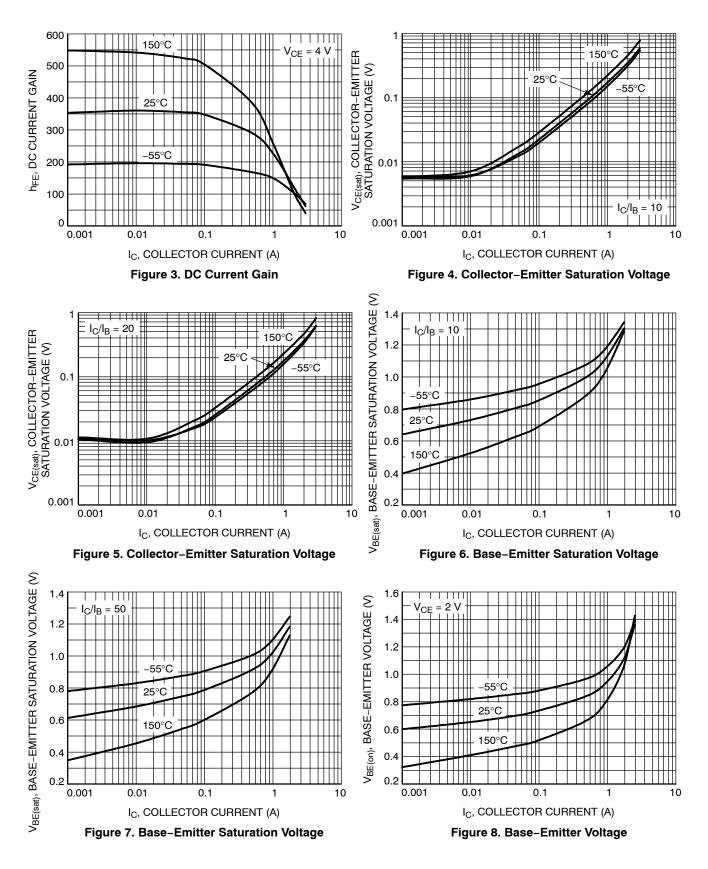
Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage $(I_{C} = 10 \text{ mAdc}, I_{B} = 0)$	V _{(BR)CEO}	20			Vdc
Collector – Base Breakdown Voltage $(I_{C} = 0.1 \text{ mAdc}, I_{E} = 0)$	V _{(BR)CBO}	40			Vdc
Emitter – Base Breakdown Voltage $(I_E = 0.1 \text{ mAdc}, I_C = 0)$	V _{(BR)EBO}	6.0			Vdc
Collector Cutoff Current ($V_{CB} = 30 \text{ Vdc}, I_E = 0$)	I _{CBO}			0.1	μAdc
Emitter Cutoff Current (V _{EB} = 5.0 Vdc)	I _{EBO}			0.1	μAdc
ON CHARACTERISTICS					
DC Current Gain (Note 3) (I _C = 10 mA, V _{CE} = 2.0 V) (I _C = 100 mA, V _{CE} = 2.0 V) (I _C = 500 mA, V _{CE} = 2.0 V) (I _C = 1.0 A, V _{CE} = 2.0 V)	h _{FE}	200 200 150 100		500	
Collector – Emitter Saturation Voltage (Note 3) ($I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$) ($I_C = 0.10 \text{ A}, I_B = 0.010 \text{ A}$) ($I_C = 0.5 \text{ A}, I_B = 0.050 \text{ A}$) ($I_C = 1.0 \text{ A}, I_B = 0.1 \text{ A}$)	V _{CE(sat)}			0.015 0.040 0.115 0.220	V
Base – Emitter Saturation Voltage (Note 3) $(I_C = 0.5 A, I_B = 50 mA)$	V _{BE(sat)}			1.1	V
Base – Emitter Turn–on Voltage (Note 3) (I _C = 0.5 A, V _{CE} = 2.0 V)	V _{BE(on)}			0.90	V
Cutoff Frequency ($I_C = 100 \text{ mA}, V_{CE} = 2.0 \text{ V}, f = 100 \text{ MHz}$)	f _T		350		MHz
Input Capacitance (V _{EB} = 0.5 V, f = 1.0 MHz)	Cibo		40		pF
Output Capacitance (V _{CB} = 4.0 V, f = 1.0 MHz)	Cobo		6		pF

3. Pulsed Condition: Pulse Width = 300 msec, Duty Cycle \leq 2%.

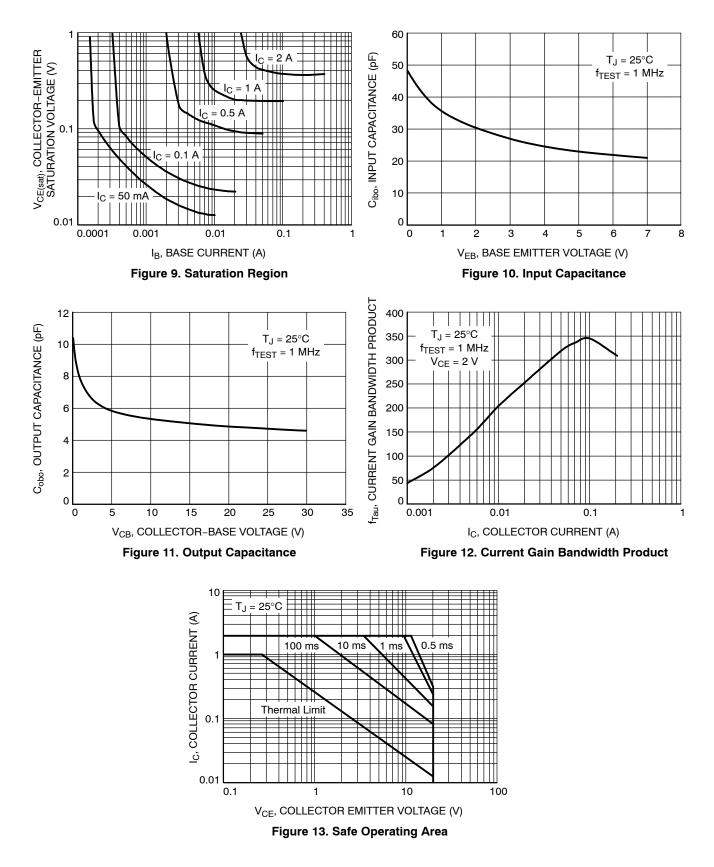
TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS



PACKAGE DIMENSIONS

SC-89 3 LEAD

CASE 463C-03 ISSUE C

> NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETERS

 CONTROLLING DIMENSION: MILLIMETERS
MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE

MATERIAL. 4. 463C-01 OBSOLETE, NEW STANDARD 463C-02.

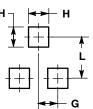
	MILLIMETERS			INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	1.50	1.60	1.70	0.059	0.063	0.067	
в	0.75	0.85	0.95	0.030	0.034	0.040	
С	0.60	0.70	0.80	0.024	0.028	0.031	
D	0.23	0.28	0.33	0.009	0.011	0.013	
G	0.50 BSC			0.020 BSC			
н	0.53 REF			0.021 REF			
J	0.10	0.15	0.20	0.004	0.006	0.008	
κ	0.30	0.40	0.50	0.012	0.016	0.020	
L	1.10 REF			0.043 REF			
М			10			10	
Ν			10 -			10	
S	1.50	1.60	1.70	0.059	0.063	0.067	

STYLE 1: PIN 1. BASE 2. EMITTER 3. COLLECTOR

SOLDERING FOOTPRINT*

SEATING PLANE

-T-1



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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